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General Description:

Silicon planar epitaxial diode. 250picofarad. 100 v max. Reverse current at 8 microampers. Q of 160 at minus 8 v. Q measured at 25 megahertz. Working voltage minus 100 at 25 deg. C. Reverse voltage minus 115 v at 25 deg. C. Maximum operating temperature 85deg. C. Temperature coefficient at minus 8 deg. 0.03 percentdeg c max. Capacity values at minus 8 v. 1 megahertz tracking error of 1 percent dim 0.350 in. X 0.350 in. X 0.150 in. Bevel on lower edge. Two wire leads located 1 on each end. Wire leads 0.030 in. Dia. 1.44 in long

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli